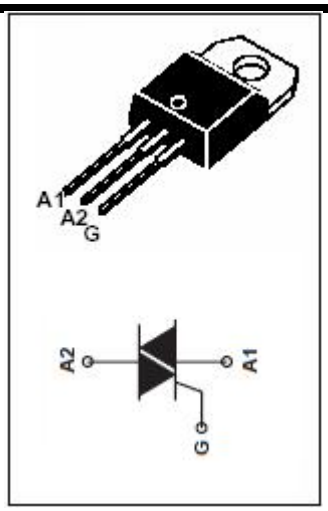
isc Triacs BTA24-600CW



FEATURES

- With TO-220AB insulated package
- Suitables for general purpose
  where high surge current capability is required.
  Application such as phase control
  and tatic switching on inductive or resistive load.
- Minimum Lot-to-Lot variations for robust device
  performance and reliable operation

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	MIN	UNIT
V_{DRM}	Repetitive peak off-state voltage	600	V
V_{RRM}	Repetitive peak reverse voltage	600	V
$I_{T(RMS)}$	RMS on-state current (full sine wave)T_j=90℃	25	A
I_{TSM}	Non-repetitive peak on-state current t_p=8.3ms	260	A
T_j	Operating junction temperature	125	℃
T_{stg}	Storage temperature	-45~150	℃
$P_{G(AV)}$	Average gate power dissipation(T_j=125℃)	1	W
$R_{th(j-c)}$	Thermal resistance, junction to case	1.5	℃/W
$R_{th(j-a)}$	Thermal resistance, junction to ambient	50	℃/W

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ELECTRICAL CHARACTERISTICS (T_C=25℃ unless otherwise specified)

SYMBOL	PARAMETER		CONDITIONS	MAX	UNIT
I_{RRM}	Repetitive peak reverse current		V_R=V_{RRM}, V_R=V_{RRM}, Tj=125℃	0.01 3.0	mA
I_{DRM}	Repetitive peak off-state current		V_D=V_{DRM}, V_D=V_{DRM}, Tj=125℃	0.01 3.0	mA
I_{GT}	Gate trigger current	I	V_D=12V; R_L= 33Ω	35	mA
		II		35	
		III		35	
I_H	Holding current		I_{GT}= 0.5A, Gate Open	50	mA
V_{GT}	Gate trigger voltage all quadrant		V_D=12V; R_L= 33Ω	1.3	V
V_{TM}	On-state voltage		I_T= 35A; t_p= 380μs	1.55	V